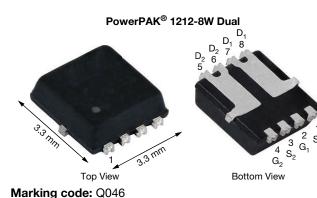
SQS940ELNW

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Vishay Siliconix

Automotive Dual N-Channel 40 V (D-S) 175 °C MOSFET



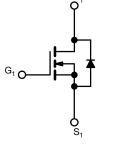
PRODUCT SUMMARY				
V _{DS} (V)	40			
$R_{DS(on)} (\Omega)$ at $V_{GS} = 10 V$	0.0203			
$R_{DS(on)} (\Omega)$ at $V_{GS} = 4.5 V$	0.0246			
I _D (A)	6			
Configuration	Dual			
Package	PowerPAK 1212-8W			

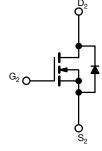
FEATURES

- TrenchFET[®] power MOSFET
- AEC-Q101 qualified
- 100 % R_q and UIS tested
- Material categorization: for definitions of compliance please see <u>www.vishay.com/doc?99912</u>



RoHS COMPLIANT HALOGEN FREE





N-Channel MOSFET

N-Channel MOSFET

ABSOLUTE MAXIMUM RATINGS ($T_C = 25 \text{ °C}$, unless otherwise noted)						
PARAMETER		SYMBOL	LIMIT	UNIT		
Drain-source voltage		V _{DS}	40	v		
Gate-source voltage		V _{GS}	± 20			
Continuous drain current ^a	T _C = 25 °C	I	6			
	T _C = 125 °C	I _D	6			
Continuous source current (diode conduction) ^a	I _S	6	А			
Pulsed drain current ^b	I _{DM}	24				
Single pulse avalanche current	L = 0.1 mH	I _{AS}	13.5			
Single pulse avalanche energy		E _{AS}	9	mJ		
Maximum power dissipation ^b	T _C = 25 °C	P	33	W		
Maximum power dissipation ~	T _C = 125 °C	P _D	11	vv		
Operating junction and storage temperature range		T _J , T _{stg}	-55 to +175	°C		
Soldering recommendations (peak temperature) e, f		260	C			

THERMAL RESISTANCE RATINGS						
PARAMETER		SYMBOL	LIMIT	UNIT		
Junction-to-ambient	PCB mount ^c	R _{thJA}	94	°C/W		
Junction-to-case (drain)		R _{thJC}	4.5	0/10		

Notes

- a. Package limited
- b. Pulse test; pulse width $\leq 300~\mu\text{s},~\text{duty}~\text{cycle} \leq 2~\%$
- c. When mounted on 1" square PCB (FR4 material)
- d. Parametric verification ongoing
- e. See solder profile (<u>www.vishay.com/doc?73257</u>). The PowerPAK 1212-8W is a leadless package. The end of the lead terminal is exposed copper (not plated) as a result of the singulation process in manufacturing. A solder fillet at the exposed copper tip cannot be guaranteed and is not required to ensure adequate bottom side solder interconnection
- f. Rework conditions: manual soldering with a soldering iron is not recommended for leadless components

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SQS940ELNW

PARAMETER	SYMBOL	TEST CONDITIONS		MIN.	TYP.	MAX.	UNIT
Static							
Drain-source breakdown voltage	V _{DS}	$V_{GS}=0,\ I_D=250\ \mu A$		40	-	-	v
Gate-source threshold voltage	V _{GS(th)}	V _{DS} =	$V_{DS} = V_{GS}, I_D = 250 \ \mu A$		2.0	2.5	v
Gate-source leakage	I _{GSS}	V _{DS} =	$V_{DS} = 0 V, V_{GS} = \pm 20 V$		-	± 100	nA
Zero gate voltage drain current	I _{DSS}	$V_{GS} = 0 V$	V _{DS} = 40 V	-	-	1	μA
		$V_{GS} = 0 V$	$V_{DS} = 40 \text{ V}, \text{ T}_{J} = 125 ^{\circ}\text{C}$	-	-	50	
		$V_{GS} = 0 V$	$V_{DS} = 40 \text{ V}, \text{ T}_{J} = 175 ^{\circ}\text{C}$	-	-	150	
On-state drain current ^a	I _{D(on)}	V _{GS} = 10 V	$V_{DS} \ge 5 V$	13	-	-	А
		$V_{GS} = 10 \text{ V}$	I _D = 1.25 A	-	0.0169	0.0203	
	-	$V_{GS} = 10 \text{ V}$	I _D = 1.25 A, T _J = 125 °C	-	-	0.030	
Drain-source on-state resistance ^a	R _{DS(on)}	V _{GS} = 10 V	I _D = 1.25 A, T _J = 175 °C	-	-	0.0337	Ω
		V _{GS} = 4.5 V	I _D = 1.25 A	-	0.0197	0.0246	
Forward transconductance ^b	9 _{fs}	V _{DS}	= 15 V, I _D = 6 A	-	25	-	S
Dynamic ^b					1	<u> </u>	1
Input capacitance	C _{iss}		V _{DS} = 25 V, f = 1 MHz	-	719	1007	pF
Output capacitance	Coss	$V_{GS} = 0 V$		-	198	278	
Reverse transfer capacitance	C _{rss}			-	20	28	
Total gate charge ^c	Qg			-	13	20	nC
Gate-source charge ^c	Q _{gs}	V _{GS} = 10 V	$V_{DS} = 20 \text{ V}, \text{ I}_{D} = 2 \text{ A}$	-	3	-	
Gate-drain charge ^c	Q _{gd}			-	3	-	
Gate resistance	R _g	f = 1 MHz		2.7	5.5	8.3	Ω
Turn-on delay time ^c	t _{d(on)}				11	17	
Rise time ^c	t _r	$\label{eq:VDD} \begin{array}{l} V_{\text{DD}} = \text{20 V}, \ R_{\text{L}} = \text{10 } \Omega \\ I_{\text{D}} \cong \text{1.5 A}, \ V_{\text{GEN}} = \text{10 V}, \ R_{\text{g}} = \text{1} \ \Omega \end{array}$		-	4	8	ns
Turn-off delay time ^c	t _{d(off)}			-	21	32	
Fall time ^c	t _f			-	5	9	
Source-Drain Diode Ratings and Charact	eristic ^b	<u>.</u>					
Pulsed current ^a	I _{SM}			-	-	24	А
Forward voltage	V _{SD}	I _F = 6 A, V _{GS} = 0 V		-	0.82	1.1	V
Body diode reverse recovery time	t _{rr}	I _F = 1 A, di/dt = 100 A/μs		-	19	38	ns
Body diode reverse recovery charge	Q _{rr}			-	10	20	nC
Reverse recovery fall time	t _a			-	9	-	- ns
Reverse recovery rise time	t _b			-	10	-	
Body diode peak reverse recovery current	I _{RM(REC)}			-	-1.3	-	А

Notes

a. Pulse test; pulse width $\leq 300~\mu\text{s},$ duty cycle $\leq 2~\%$

b. Guaranteed by design, not subject to production testing

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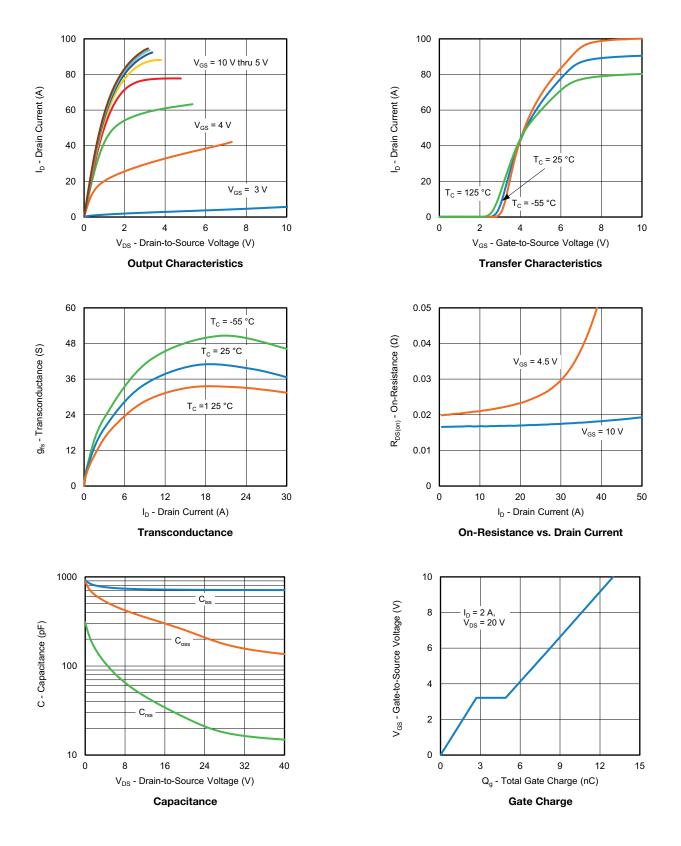
c. Independent of operating temperature

Stresses beyond those listed under "Absolute Maximum Ratings" may cause permanent damage to the device. These are stress ratings only, and functional operation of the device at these or any other conditions beyond those indicated in the operational sections of the specifications is not implied. Exposure to absolute maximum rating conditions for extended periods may affect device reliability.

2



TYPICAL CHARACTERISTICS (T_A = 25 °C, unless otherwise noted)



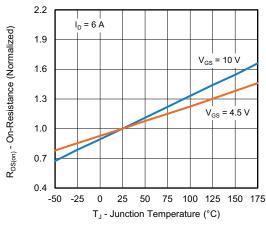
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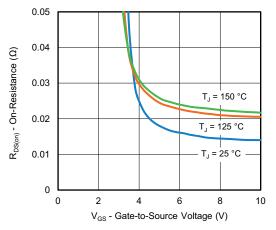
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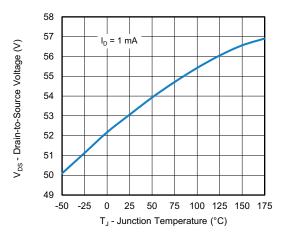
TYPICAL CHARACTERISTICS ($T_A = 25 \text{ °C}$, unless otherwise noted)



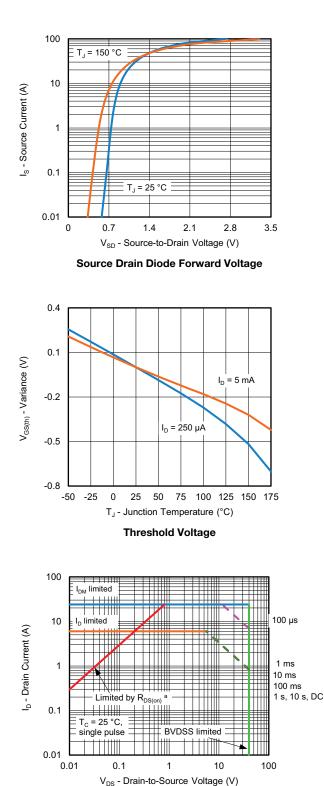
On-Resistance vs. Junction Temperature



On-Resistance vs. Gate-to-Source Voltage



Drain Source Breakdown vs. Junction Temperature



Safe Operating Area



a. V_{GS} > minimum V_{GS} at which $R_{DS(on)}$ is specified

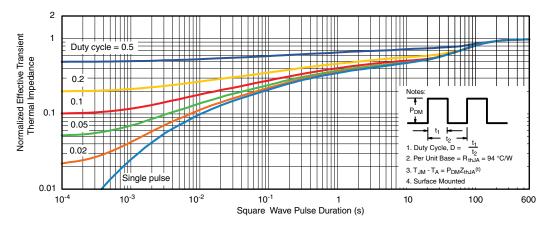
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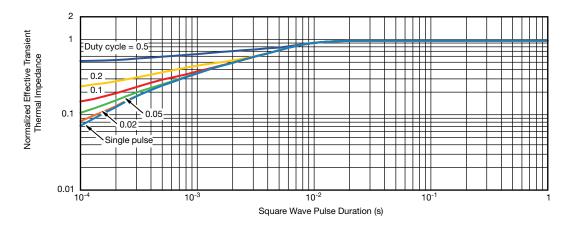
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THERMAL RATINGS (T_A = 25 °C, unless otherwise noted)



Normalized Thermal Transient Impedance, Junction-to-Ambient



Normalized Thermal Transient Impedance, Junction-to-Case

Note

- The characteristics shown in the two graphs
 - Normalized Transient Thermal Impedance Junction-to-Ambient (25 °C)
- Normalized Transient Thermal Impedance Junction-to-Case (25 °C)

are given for general guidelines only to enable the user to get a "ball park" indication of part capabilities. The data are extracted from single pulse transient thermal impedance characteristics which are developed from empirical measurements. The latter is valid for the part mounted on printed circuit board - FR4, size 1" x 1" x 0.062", double sided with 2 oz. copper, 100 % on both sides. The part capabilities can widely vary depending on actual application parameters and operating conditions

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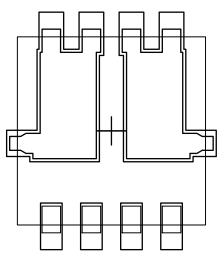
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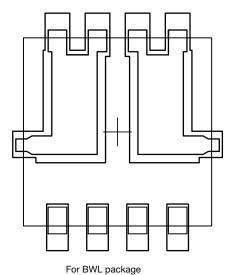
PAD Pattern



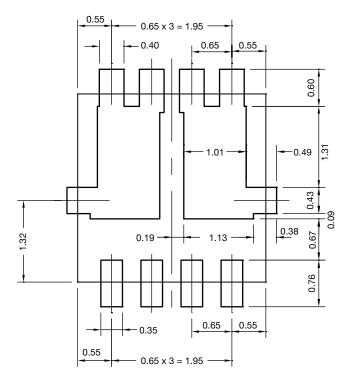
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Recommended Land Pattern for PowerPAK® 1212-8 Dual











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